



# MAX3232E 3-V to 5.5-V Multichannel RS-232 Line Driver and Receiver

## With $\pm 15$ -kV IEC ESD Protection

### 1 Features

- ESD Protection for RS-232 Bus Pins
  - $\pm 15$  kV (HBM)
  - $\pm 8$  kV (IEC61000-4-2, Contact Discharge)
  - $\pm 15$  kV (IEC61000-4-2, Air-Gap Discharge)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU V.28 Standards
- Operates With 3-V to 5.5-V  $V_{CC}$  Supply
- Operates up to 250 kbit/s
- Two Drivers and Two Receivers
- Low Supply Current: 300  $\mu$ A (Typical)
- External Capacitors:  $4 \times 0.1 \mu$ F
- Accepts 5-V Logic Input With 3.3-V Supply
- Pin Compatible to Alternative High-Speed Devices (1 Mbit/s)
  - SN65C3232E ( $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ )
  - SN75C3232E ( $0^{\circ}\text{C}$  to  $70^{\circ}\text{C}$ )

### 2 Applications

- Battery-Powered Systems
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

### 3 Description

The MAX3232E device consists of two line drivers, two-line receivers, and a dual charge-pump circuit with  $\pm 15$ -kV IEC ESD protection pin to pin (serial-port connection pins, including GND).

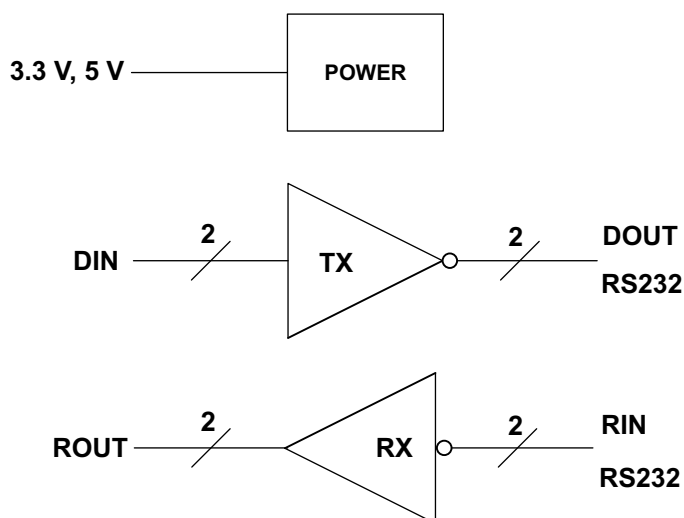
The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The devices operate at data signaling rates up to 250 kbit/s and a maximum of 30-V/ $\mu$ s driver output slew rate.

**Device Information<sup>(1)</sup>**

| PART NUMBER | PACKAGE    | BODY SIZE (NOM)           |
|-------------|------------|---------------------------|
| MAX3232ExD  | SOIC (16)  | 9.90 mm $\times$ 3.91 mm  |
| MAX3232ExDB | SSOP (16)  | 6.20 mm $\times$ 5.30 mm  |
| MAX3232ExDW | SOIC (16)  | 10.30 mm $\times$ 7.50 mm |
| MAX3232ExPW | TSSOP (16) | 5.00 mm $\times$ 4.40 mm  |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

**Simplified Diagram**



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## 4 Revision History

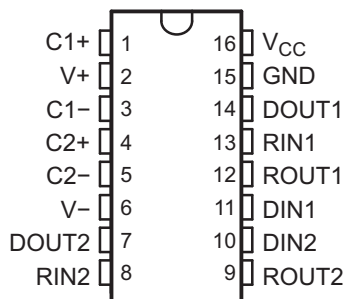
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision B (December 2013) to Revision C  | Page |
|--|------|
| <ul style="list-style-type: none"> <li>Added <i>Device Information</i> table, <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i>, <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section .....</li> </ul> | 1    |

| Changes from Revision A (April 2007) to Revision B  | Page        |
|---|-------------|
| <ul style="list-style-type: none"> <li>Updated document to new TI data sheet format. ....</li> <li>Deleted <i>Ordering Information</i> table. ....</li> <li>Added <i>Thermal Information</i> table. ....</li> </ul> | 1<br>1<br>5 |

## 5 Pin Configuration and Functions

**D, DW, DB and PW Package  
16-Pin SOIC, SSOP and TSSOP  
Top View**



**Pin Functions**

| PIN             |     | I/O | DESCRIPTION   |
|-----------------|-----|-----|---|
| NAME            | NO. |     |   |
| C1+             | 1   | —   | Positive lead of C1 capacitor                                 |
| V+              | 2   | O   | Positive charge pump output for storage capacitor only        |
| C1–             | 3   | —   | Negative lead of C1 capacitor                                 |
| C2+             | 4   | —   | Positive lead of C2 capacitor                                 |
| C2–             | 5   | —   | Negative lead of C2 capacitor                                 |
| V–              | 6   | O   | Negative charge pump output for storage capacitor only        |
| DOUT2           | 7   | O   | RS232 line data output (to remote RS232 system)               |
| RIN2            | 8   | I   | RS232 line data input (from remote RS232 system)              |
| ROUT2           | 9   | O   | Logic data output (to UART)                                   |
| DIN2            | 10  | I   | Logic data input (from UART)                                  |
| DIN1            | 11  | I   | Logic data input (from UART)                                  |
| ROUT1           | 12  | O   | Logic data output (to UART)                                   |
| RIN1            | 13  | I   | RS232 line data input (from remote RS232 system)              |
| DOUT1           | 14  | O   | RS232 line data output (to remote RS232 system)               |
| GND             | 15  | —   | Ground  |
| V <sub>CC</sub> | 16  | —   | Supply Voltage, Connect to external 3-V to 5.5-V power supply |

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                  |   |           | MIN   | MAX                   | UNIT |
|------------------|---|-----------|-------|-----------------------|------|
| V <sub>CC</sub>  | Supply voltage <sup>(2)</sup>                 |           | −0.3  | 6                     | V    |
| V+               | Positive output supply voltage <sup>(2)</sup> |           | −0.3  | 7                     | V    |
| V−               | Negative output supply voltage <sup>(2)</sup> |           | 0.3   | −7                    | V    |
| V+ − V−          | Supply voltage difference <sup>(2)</sup>      |           |       | 13                    | V    |
| V <sub>I</sub>   | Input voltage                                 | Drivers   | −0.3  | 6                     | V    |
|                  |   | Receivers | −25   | 25                    | V    |
| V <sub>O</sub>   | Output voltage                                | Drivers   | −13.2 | 13.2                  | V    |
|                  |   | Receivers | −0.3  | V <sub>CC</sub> + 0.3 | V    |
| T <sub>J</sub>   | Operating virtual junction temperature        |           |       | 150                   | °C   |
| T <sub>stg</sub> | Storage temperature                           |           | −65   | 150                   | °C   |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to network GND.

### 6.2 ESD Ratings

|                    |                         |  | VALUE                        | UNIT    |
|--------------------|-------------------------|--|------------------------------|---------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | All pins except RIN and DOUT | ±2000   |
|                    |                         |  | RIN and DOUT Pins            | ±15,000 |
|                    |                         | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | All pins                     | ±1500   |
|                    |                         | IEC61000-4-2, Contact Discharge  | RS232 port pins (RIN, DOUT)  | ±8000   |
|                    |                         | IEC61000-4-2, Air-Gap Discharge  | RS232 port pins (RIN, DOUT)  | ±15,000 |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions<sup>(1)</sup>

See [Figure 7](#).

|                 |                                 |                         | MIN | NOM | MAX | UNIT |
|-----------------|---------------------------------|-------------------------|-----|-----|-----|------|
| Supply voltage  |                                 | V <sub>CC</sub> = 3.3 V | 3   | 3.3 | 3.6 | V    |
|                 |                                 | V <sub>CC</sub> = 5 V   | 4.5 | 5   | 5.5 |      |
| V <sub>IH</sub> | Driver high-level input voltage | DIN                     | 2   |     | 5.5 | V    |
|                 |                                 |                         |     |     | 5.5 |      |
| V <sub>IL</sub> | Driver low-level input voltage  | DIN                     | 0   |     | 0.8 | V    |
| V <sub>I</sub>  | Receiver input voltage          | RIN                     | −25 |     | 25  | V    |
| T <sub>A</sub>  | Operating free-air temperature  | MAX3232EC               | 0   |     | 70  | °C   |
|                 |                                 | MAX3232EI               | −40 |     | 85  |      |

(1) Test conditions are C1–C4 = 0.1 μF at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V<sub>CC</sub> = 5 V ± 0.5 V.

## 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |  | MAX3232E   |          |           |           | UNIT |
|-------------------------------|--|------------|----------|-----------|-----------|------|
|                               |  | PW (TSSOP) | D (SOIC) | DW (SOIC) | DB (SSOP) |      |
|                               |  | 16 PINS    | 16 PINS  | 16 PINS   | 16 PINS   |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 99.3       | 76.1     | 72.3      | 90.9      | °C/W |
| R <sub>θJCTop</sub>           | Junction-to-case (top) thermal resistance    | 20.8       | 36.7     | 33.5      | 36.2      | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 45.1       | 33.6     | 37.1      | 43.8      | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 0.6        | 4.2      | 7.5       | 4.2       | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 45.1       | 33.3     | 37.1      | 42.9      | °C/W |
| R <sub>θJCbott</sub>          | Junction-to-case (bottom) thermal resistance | –          | –        | –         | –         | °C/W |

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 6.5 Electrical Characteristics — Device<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 7](#)).

| PARAMETER                      | TEST CONDITIONS                         | MIN | TYP <sup>(2)</sup> | MAX | UNIT |
|--------------------------------|---|-----|--------------------|-----|------|
| I <sub>CC</sub> Supply current | No load, V <sub>CC</sub> = 3.3 V or 5 V |     | 0.3                | 1   | mA   |

(1) Test conditions are C1–C4 = 0.1 μF at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V<sub>CC</sub> = 5 V ± 0.5 V.

(2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

## 6.6 Electrical Characteristics — Driver<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted) (see [Figure 7](#)).

| PARAMETER   | TEST CONDITIONS  | MIN | TYP <sup>(2)</sup> | MAX | UNIT |
|---|--|-----|--------------------|-----|------|
| V <sub>OH</sub> High-level output voltage                   | DOUT at R <sub>L</sub> = 3 kΩ to GND, DIN = GND                                    | 5   | 5.4                |     | V    |
| V <sub>OL</sub> Low-level output voltage                    | DOUT at R <sub>L</sub> = 3 kΩ to GND, DIN = V <sub>CC</sub>                        | –5  | –5.4               |     | V    |
| I <sub>IH</sub> High-level input current                    | V <sub>I</sub> = V <sub>CC</sub>   |     | ±0.01              | ±1  | μA   |
| I <sub>IL</sub> Low-level input current                     | V <sub>I</sub> at GND  |     | ±0.01              | ±1  | μA   |
| I <sub>OS</sub> <sup>(3)</sup> Short-circuit output current | V <sub>CC</sub> = 3.6 V, V <sub>O</sub> = 0 V                                      |     | ±35                | ±60 | mA   |
|   | V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 0 V                                      |     |                    |     |      |
| r <sub>O</sub> Output resistance                            | V <sub>CC</sub> , V <sub>I</sub> , and V <sub>O</sub> = 0 V, V <sub>O</sub> = ±2 V | 300 | 10M                |     | Ω    |

(1) Test conditions are C1–C4 = 0.1 μF at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V<sub>CC</sub> = 5 V ± 0.5 V.

(2) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

(3) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

## 6.7 Electrical Characteristics — Receiver<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 7](#)).

| PARAMETER  | TEST CONDITIONS                | MIN                   | TYP <sup>(2)</sup>    | MAX | UNIT |
|--|--------------------------------|-----------------------|-----------------------|-----|------|
| V <sub>OH</sub> High-level output voltage                                | I <sub>OH</sub> = –1 mA        | V <sub>CC</sub> – 0.6 | V <sub>CC</sub> – 0.1 |     | V    |
| V <sub>OL</sub> Low-level output voltage                                 | I <sub>OL</sub> = 1.6 mA       |                       |                       | 0.4 | V    |
| V <sub>IT+</sub> Positive-going input threshold voltage                  | V <sub>CC</sub> = 3.3 V        |                       | 1.5                   | 2.4 | V    |
|  | V <sub>CC</sub> = 5 V          |                       | 1.8                   | 2.4 |      |
| V <sub>IT–</sub> Negative-going input threshold voltage                  | V <sub>CC</sub> = 3.3 V        | 0.6                   | 1.2                   |     | V    |
|  | V <sub>CC</sub> = 5 V          | 0.8                   | 1.5                   |     |      |
| V <sub>hys</sub> Input hysteresis (V <sub>IT+</sub> – V <sub>IT–</sub> ) |                                |                       | 0.3                   |     | V    |
| r <sub>i</sub> Input resistance  | V <sub>I</sub> = ±3 V to ±25 V | 3                     | 5                     | 7   | kΩ   |

(1) Test conditions are C1–C4 = 0.1 μF at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V<sub>CC</sub> = 5 V ± 0.5 V.

(2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

## 6.8 Switching Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see [Figure 7](#))

| PARAMETER   | TEST CONDITIONS   | MIN                                       | TYP <sup>(2)</sup> | MAX | UNIT   |
|---|---|---|--------------------|-----|--------|
| Maximum data rate   | $R_L = 3\text{ k}\Omega$ ,<br>One DOUT switching,<br>$C_L = 1000\text{ pF}$ ,<br>see <a href="#">Figure 3</a>                   | 150                                       | 250                |     | kbit/s |
| $t_{sk(p)}$ Driver pulse skew <sup>(3)</sup>                                  | $R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ ,<br>see <a href="#">Figure 4</a><br>$C_L = 150\text{ pF}$ to $2500\text{ pF}$ , |   | 300                |     | ns     |
| SR(tr) Driver slew rate, transition region<br>(see <a href="#">Figure 3</a> ) | $R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$ ,<br>$V_{CC} = 3.3\text{ V}$   | $C_L = 150\text{ pF}$ to $1000\text{ pF}$ |                    | 6   | 30     |
|   |   | $C_L = 150\text{ pF}$ to $2500\text{ pF}$ |                    | 4   | 30     |
| $t_{PLH}$ Receiver propagation delay time, low- to high-level output          | $C_L = 150\text{ pF}$ ,<br>see <a href="#">Figure 5</a>   |   |                    | 300 | ns     |
| $t_{PHL}$ Receiver propagation delay time, high- to low-level output          |   |   |                    | 300 | ns     |
| $t_{sk(p)}$ Receiver pulse skew <sup>(3)</sup>                                |   |   |                    | 300 | ns     |

(1) Test conditions are  $C1-C4 = 0.1\text{ }\mu\text{F}$  at  $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ ;  $C1 = 0.047\text{ }\mu\text{F}$ ,  $C2-C4 = 0.33\text{ }\mu\text{F}$  at  $V_{CC} = 5\text{ V} \pm 0.5\text{ V}$ .

(2) All typical values are at  $V_{CC} = 3.3\text{ V}$  or  $V_{CC} = 5\text{ V}$ , and  $T_A = 25^\circ\text{C}$ .

(3) Pulse skew is defined as  $|t_{PLH} - t_{PHL}|$  of each channel of the same device.

## 6.9 Typical Characteristics

$V_{CC} = 3.3\text{ V}$

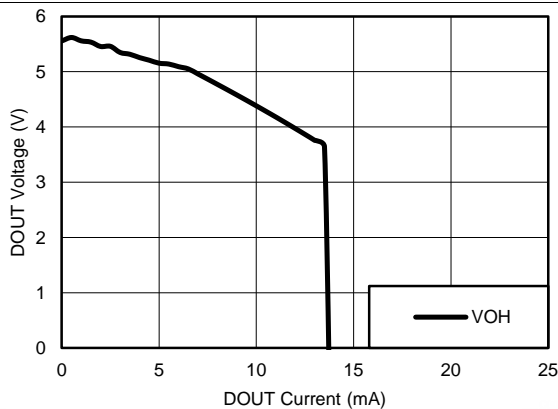


Figure 1. DOUT  $V_{OH}$  vs Load Current, Both Drivers Loaded

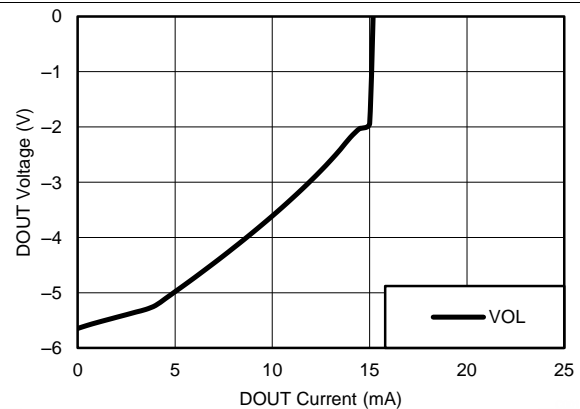
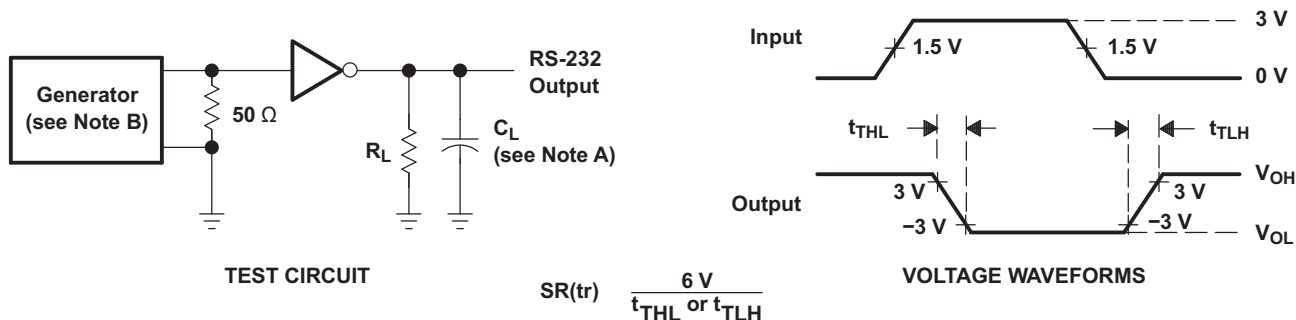


Figure 2. DOUT  $V_{OL}$  vs Load Current, Both Drivers Loaded

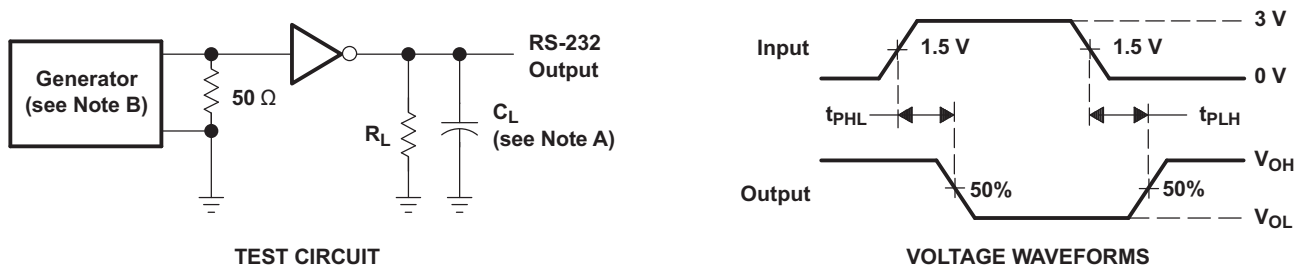
## 7 Parameter Measurement Information



A.  $C_L$  includes probe and jig capacitance

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50\ \Omega$ , 50% duty cycle,  $t_r \leq 10\text{ ns}$ ,  $t_f \leq 10\text{ ns}$

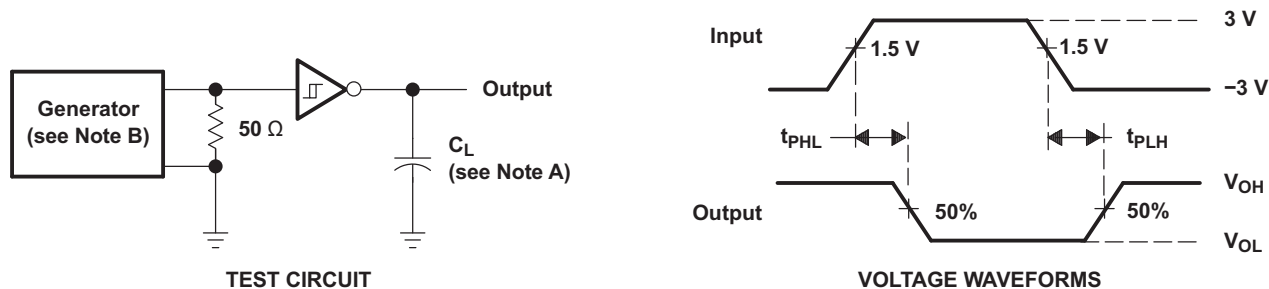
Figure 3. Driver Slew Rate



A.  $C_L$  includes probe and jig capacitance

B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_O = 50\ \Omega$ , 50% duty cycle,  $t_r \leq 10\text{ ns}$ ,  $t_f \leq 10\text{ ns}$

Figure 4. Driver Pulse Skew



A.  $C_L$  includes probe and jig capacitance

B. The pulse generator has the following characteristics:  $Z_O = 50\ \Omega$ , 50% duty cycle,  $t_r \leq 10\text{ ns}$ ,  $t_f \leq 10\text{ ns}$

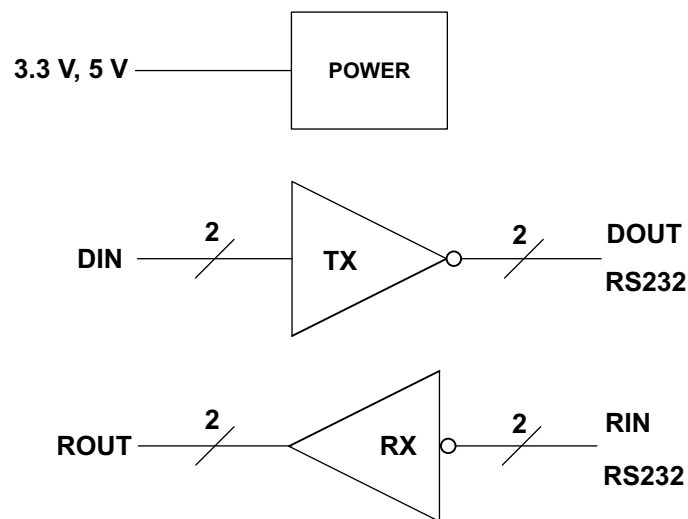
Figure 5. Receiver Propagation Delay Times

## 8 Detailed Description

### 8.1 Overview

The MAX3232E device consists of two line drivers, two-line receivers, and a dual charge-pump circuit with IEC61000-4-2 ESD protection terminal to terminal (serial-port connection terminals, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The device operates at data signaling rates up to 250 kbit/s and a maximum of 30-V/ $\mu$ s driver output slew rate. Outputs are protected against shorts to ground.

### 8.2 Functional Block Diagram



### 8.3 Feature Description

#### 8.3.1 Power

The power block increases, inverts, and regulates voltage at V+ and V– pins using a charge pump that requires four external capacitors.

#### 8.3.2 RS232 Driver

Two drivers interface standard logic level to RS232 levels. Both DIN inputs must be valid high or low.

#### 8.3.3 RS232 Receiver

Two receivers interface RS232 levels to standard logic levels. An open input will result in a high output on ROUT. Each RIN input includes an internal standard RS232 load.



## 8.4 Device Functional Modes

Table 1 and Table 2 list the functional modes of the drivers and receivers of MAX3232E.

**Table 1. Each Driver<sup>(1)</sup>**

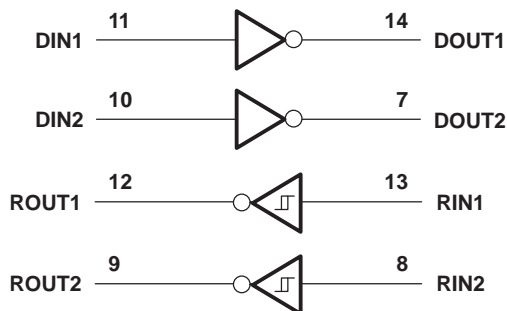
| INPUT<br>DIN | OUTPUT<br>DOUT |
|--------------|----------------|
| L            | H              |
| H            | L              |

(1) H = high level, L = low level

**Table 2. Each Receiver<sup>(1)</sup>**

| INPUT<br>RIN | OUTPUT<br>ROUT |
|--------------|----------------|
| L            | H              |
| H            | L              |
| Open         | H              |

(1) H = high level, L = low level,  
Open = input disconnected or connected driver off



**Figure 6. Logic Diagram**

### 8.4.1 $V_{CC}$ Powered by 3 V to 5.5 V

The device is in normal operation.

### 8.4.2 $V_{CC}$ Unpowered, $V_{CC} = 0$ V

When MAX3232E is unpowered, it can be safely connected to an active remote RS232 device.

## 9 Applications and Implementation

### NOTE

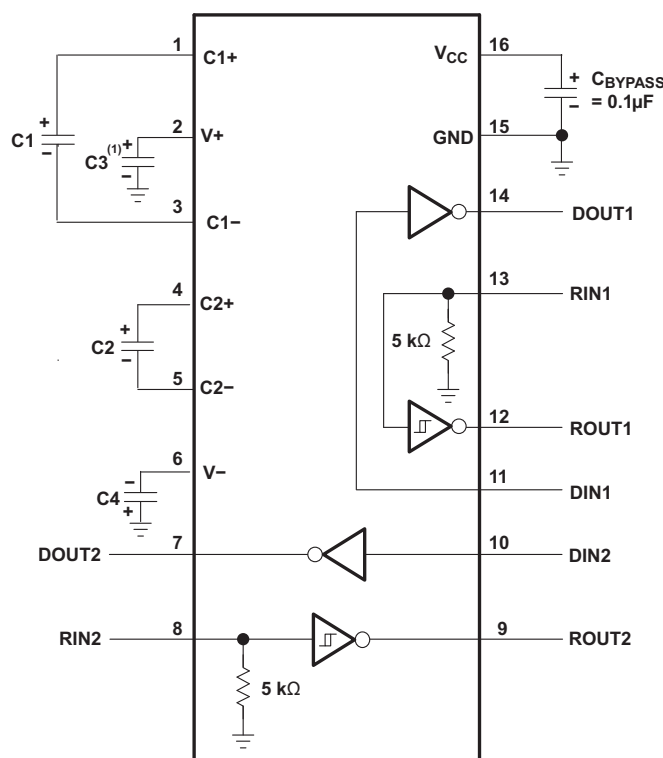
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

For proper operation, add capacitors as shown in [Table 3](#).

### 9.2 Typical Application

ROUT and DIN connect to UART or general-purpose logic lines. RIN and DOUT lines connect to a RS232 connector or cable.



(1) C3 can be connected to  $V_{CC}$  or GND

Notes: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

**Figure 7. Typical Operating Circuit and Capacitor Values**

**Table 3. VCC vs Capacitor Values**

| $V_{CC}$          | C1            | C2, C3, C4   |
|-------------------|---------------|--------------|
| 3.3 V $\pm$ 0.3 V | 0.1 $\mu$ F   | 0.1 $\mu$ F  |
| 5 V $\pm$ 0.5 V   | 0.047 $\mu$ F | 0.33 $\mu$ F |
| 3 V $\pm$ 5.5 V   | 0.1 $\mu$ F   | 0.47 $\mu$ F |

### 9.2.1 Design Requirements

The recommended  $V_{CC}$  is 3.3 V or 5 V. 3 V to 5.5 V is also possible

The maximum recommended bit rate is 250 kbit/s.

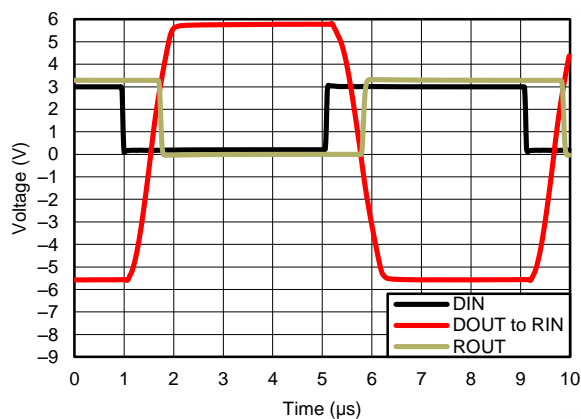
### 9.2.2 Detailed Design Procedure

All DIN inputs must be connected to valid low or high logic levels.

Select capacitor values based on  $V_{CC}$  level for best performance.

### 9.2.3 Application Curve

Figure 8 curves are for 3.3-V  $V_{CC}$  and 250-kbit/s alternative bit data stream.



**Figure 8. 250 kbit/s Driver to Receiver Loopback Timing Waveform,  
 $V_{CC}$  = 3.3 V**

## 10 Power Supply Recommendations

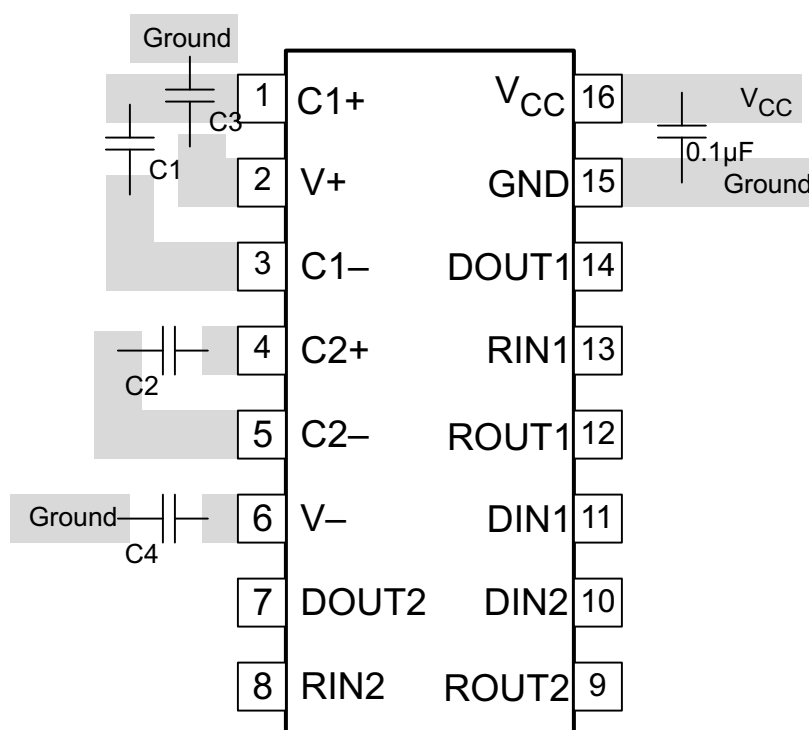
The supply voltage,  $V_{CC}$ , should be between 3 V and 5.5 V. Select the values of the charge-pump capacitors using [Table 3](#).

## 11 Layout

### 11.1 Layout Guidelines

Keep the external capacitor traces short, specifically on the C1 and C2 nodes that have the fastest rise and fall times.

### 11.2 Layout Example



**Figure 9. Layout Diagram**

## 12 Device and Documentation Support

### 12.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.2 Trademarks

E2E is a trademark of Texas Instruments.  
All other trademarks are the property of their respective owners.

### 12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| MAX3232ECD       | ACTIVE        | SOIC         | D                  | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECDB      | ACTIVE        | SSOP         | DB                 | 16   | 80             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECDBE4    | ACTIVE        | SSOP         | DB                 | 16   | 80             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECDBG4    | ACTIVE        | SSOP         | DB                 | 16   | 80             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECDBR     | ACTIVE        | SSOP         | DB                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECDBRG4   | ACTIVE        | SSOP         | DB                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECDE4     | ACTIVE        | SOIC         | D                  | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECDG4     | ACTIVE        | SOIC         | D                  | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECDR      | ACTIVE        | SOIC         | D                  | 16   | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECDRE4    | ACTIVE        | SOIC         | D                  | 16   | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECDRG4    | ACTIVE        | SOIC         | D                  | 16   | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECDW      | ACTIVE        | SOIC         | DW                 | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECDWG4    | ACTIVE        | SOIC         | DW                 | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECDWR     | ACTIVE        | SOIC         | DW                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MAX3232EC               | <a href="#">Samples</a> |
| MAX3232ECPW      | ACTIVE        | TSSOP        | PW                 | 16   | 90             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECPWE4    | ACTIVE        | TSSOP        | PW                 | 16   | 90             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECPWG4    | ACTIVE        | TSSOP        | PW                 | 16   | 90             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| MAX3232ECPWR     | ACTIVE        | TSSOP        | PW                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECPWRE4   | ACTIVE        | TSSOP        | PW                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232ECPWRG4   | ACTIVE        | TSSOP        | PW                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | 0 to 70      | MP232EC                 | <a href="#">Samples</a> |
| MAX3232EID       | ACTIVE        | SOIC         | D                  | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |
| MAX3232EIDB      | ACTIVE        | SSOP         | DB                 | 16   | 80             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIDBE4    | ACTIVE        | SSOP         | DB                 | 16   | 80             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIDBG4    | ACTIVE        | SSOP         | DB                 | 16   | 80             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIDBR     | ACTIVE        | SSOP         | DB                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIDBRE4   | ACTIVE        | SSOP         | DB                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIDBRG4   | ACTIVE        | SSOP         | DB                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIDE4     | ACTIVE        | SOIC         | D                  | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |
| MAX3232EIDG4     | ACTIVE        | SOIC         | D                  | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |
| MAX3232EIDR      | ACTIVE        | SOIC         | D                  | 16   | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |
| MAX3232EIDRE4    | ACTIVE        | SOIC         | D                  | 16   | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |
| MAX3232EIDRG4    | ACTIVE        | SOIC         | D                  | 16   | 2500           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |
| MAX3232EIDW      | ACTIVE        | SOIC         | DW                 | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |
| MAX3232EIDWG4    | ACTIVE        | SOIC         | DW                 | 16   | 40             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |
| MAX3232EIDWR     | ACTIVE        | SOIC         | DW                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MAX3232EI               | <a href="#">Samples</a> |

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2)            | Lead/Ball Finish<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|----------------------------|-------------------------|----------------------|--------------|-------------------------|-------------------------|
| MAX3232EIPW      | ACTIVE        | TSSOP        | PW                 | 16   | 90             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIPWE4    | ACTIVE        | TSSOP        | PW                 | 16   | 90             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIPWG4    | ACTIVE        | TSSOP        | PW                 | 16   | 90             | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIPWR     | ACTIVE        | TSSOP        | PW                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |
| MAX3232EIPWRG4   | ACTIVE        | TSSOP        | PW                 | 16   | 2000           | Green (RoHS<br>& no Sb/Br) | CU NIPDAU               | Level-1-260C-UNLIM   | -40 to 85    | MP232EI                 | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



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**OTHER QUALIFIED VERSIONS OF MAX3232E :**

- Automotive: [MAX3232E-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| MAX3232ECDBR | SSOP         | DB              | 16   | 2000 | 330.0              | 16.4               | 8.2     | 6.6     | 2.5     | 12.0    | 16.0   | Q1            |
| MAX3232ECDR  | SOIC         | D               | 16   | 2500 | 330.0              | 16.4               | 6.5     | 10.3    | 2.1     | 8.0     | 16.0   | Q1            |
| MAX3232ECDWR | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| MAX3232ECPWR | TSSOP        | PW              | 16   | 2000 | 330.0              | 12.4               | 6.9     | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |
| MAX3232EIDBR | SSOP         | DB              | 16   | 2000 | 330.0              | 16.4               | 8.2     | 6.6     | 2.5     | 12.0    | 16.0   | Q1            |
| MAX3232EIDR  | SOIC         | D               | 16   | 2500 | 330.0              | 16.4               | 6.5     | 10.3    | 2.1     | 8.0     | 16.0   | Q1            |
| MAX3232EIDWR | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |
| MAX3232EIPWR | TSSOP        | PW              | 16   | 2000 | 330.0              | 12.4               | 6.9     | 5.6     | 1.6     | 8.0     | 12.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| MAX3232ECDBR | SSOP         | DB              | 16   | 2000 | 367.0       | 367.0      | 38.0        |
| MAX3232ECDR  | SOIC         | D               | 16   | 2500 | 367.0       | 367.0      | 38.0        |
| MAX3232ECDWR | SOIC         | DW              | 16   | 2000 | 367.0       | 367.0      | 38.0        |
| MAX3232ECPWR | TSSOP        | PW              | 16   | 2000 | 367.0       | 367.0      | 35.0        |
| MAX3232EIDBR | SSOP         | DB              | 16   | 2000 | 367.0       | 367.0      | 38.0        |
| MAX3232EIDR  | SOIC         | D               | 16   | 2500 | 367.0       | 367.0      | 38.0        |
| MAX3232EIDWR | SOIC         | DW              | 16   | 2000 | 367.0       | 367.0      | 38.0        |
| MAX3232EIPWR | TSSOP        | PW              | 16   | 2000 | 367.0       | 367.0      | 35.0        |

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - $\Delta$  C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
  - $\Delta$  D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
  - E. Falls within JEDEC MO-153

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4211284-3/F 12/12

- NOTES:
- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

## DB (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

28 PINS SHOWN

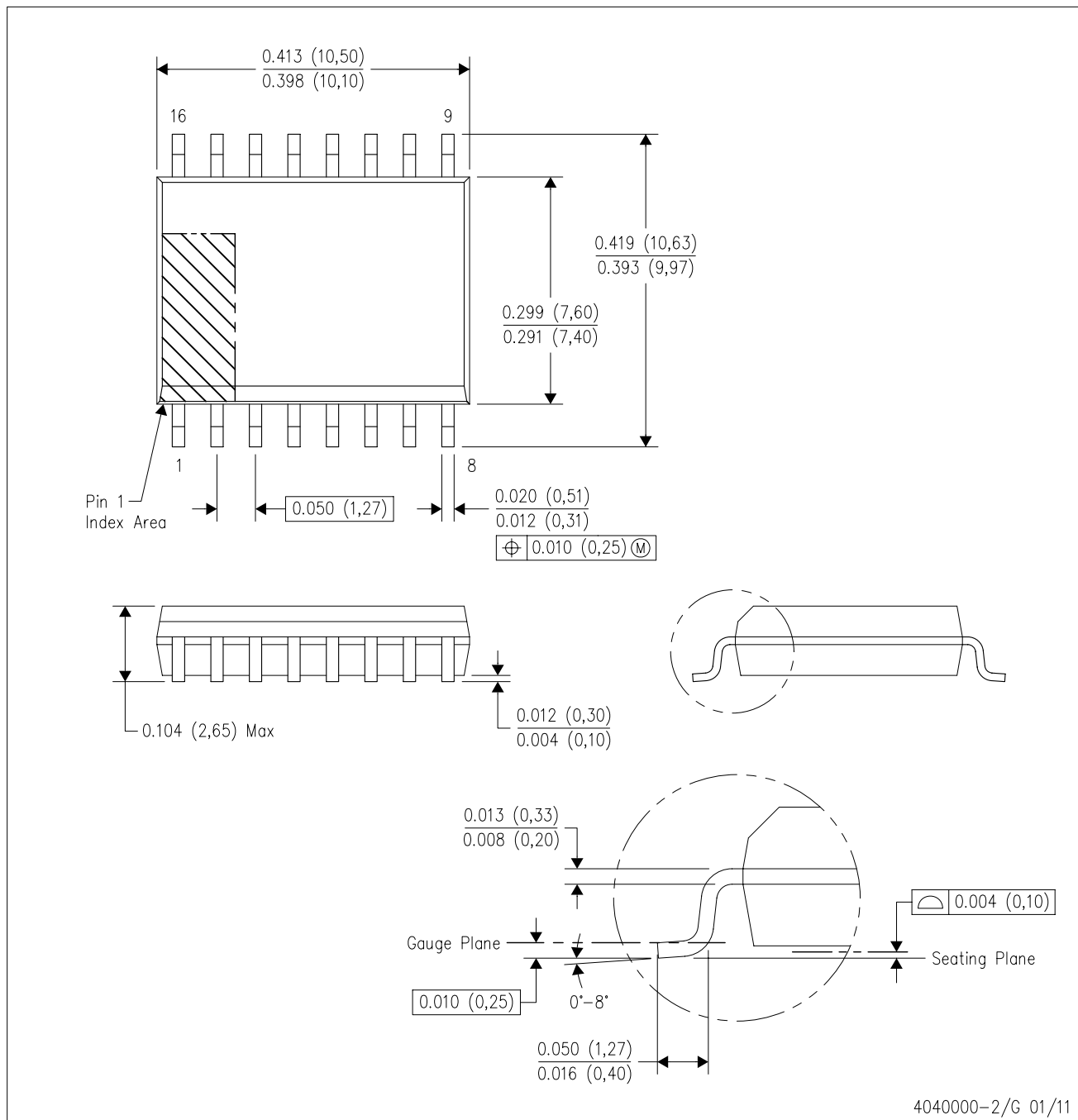


- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-150



DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
  - D. Falls within JEDEC MS-013 variation AA.

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### Products

|                              |  |
|------------------------------|--|
| Audio                        | <a href="http://www.ti.com/audio">www.ti.com/audio</a>                               |
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| Data Converters              | <a href="http://dataconverter.ti.com">dataconverter.ti.com</a>                       |
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